

## SURFACE MOUNT BI-DIRECTIONAL THYRISTOR SURGE PROTECTOR DEVICE

### FEATURES

- Protects by limiting voltages and shunting surge currents away from sensitive circuits
- Designed for telecommunications applications such as line cards, modems, PBX, FAX, LAN, VHDLSL
- Helps meet standards such as GR1089, ITU K.20, IEC950, UL1459&50, FCC part 68
- Low capacitance, High surge (A, B, C rating available), precise voltage limiting, Long life



### SUMMARY ELECTRICAL CHARACTERISTICS

Part Number	Rated Repetitive Peak Off-State Voltage	Breakover Voltage	On-State Voltage	Repetitive Peak Off-State Current	Breakover Current	Holding Current	Off-State Capacitance (f = 1 MHz, Vac = 15 mV <sub>RMS</sub> )			
	Max.	Max.	Max.	Max.	Max.	Min.	Typ.	Max.	Typ.	Max.
	V <sub>DRM</sub>	V <sub>BO @ I<sub>BO</sub></sub>	V <sub>T @ 1A</sub>	I <sub>DRM</sub>	I <sub>BO</sub>	I <sub>H</sub>	C <sub>O @ 0 V<sub>dc</sub></sub>		C <sub>O @ 50 V<sub>dc</sub></sub>	
	V	V	V	μA	mA	mA	pF		pF	
TSP058SB	58	77	5	5	800	150	70	100	24	29
TSP065SB	65	88	5	5	800	150	67	90	22	28
TSP075SB	75	98	5	5	800	150	67	78	23	27
TSP090SB	90	130	5	5	800	150	57	61	19	21
TSP120SB	120	160	5	5	800	150	50	58	17	20
TSP140SB	140	180	5	5	800	150	49	54	16	19
TSP160SB	160	220	5	5	800	150	46	53	15	18
TSP190SB	190	260	5	5	800	150	45	53	14	18
TSP220SB	220	300	5	5	800	150	44	52	13	18
TSP275SB	275	350	5	5	800	150	44	51	13	18
TSP320SB	320	400	5	5	800	150	43	50	13	17
notes	(1,3)	(3,5,6)	(3)	(3)	(3)	(2,3)	(3)	(3)	(3)	(3)

#### NOTES:

1. Specific V<sub>DRM</sub> values are available by request.
2. Specific I<sub>H</sub> values are available by request.
3. All ratings and characteristics are at 25 °C unless otherwise specified.
4. V<sub>DRM</sub> applies for the life of the device. I<sub>DRM</sub> will be in spec during and following operation of the device.
5. V<sub>BO1</sub> is at 100V/msec, I<sub>SC</sub> = 10A<sub>pk</sub>, V<sub>OC</sub> = 1KV<sub>pk</sub>, 10/1000 Waveform
6. V<sub>BO2</sub> is at f = 60 Hz, I<sub>SC</sub> = 1 A<sub>(RMS)</sub>, Vac = 1KV<sub>(RMS)</sub>, R<sub>L</sub> = 1 KΩ, 1/2 AC cycle

## SELECTION GUIDE

Follow these steps to select the proper Thyristor surge protector for your application:

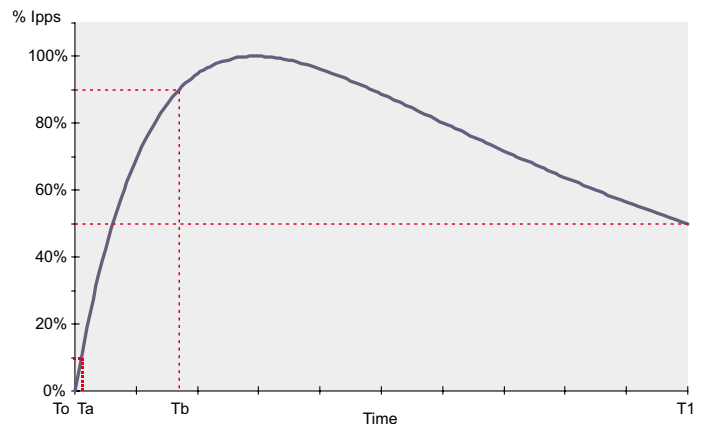
- Define the operating parameters for the circuit:
  - Ambient operating temperature range
  - Maximum telephone line operating current (highest battery and shortest copper loop)
  - Maximum operating voltage: (Maximum DC bias + peak ringing voltage)
  - Maximum surge current
  - System voltage damage threshold
  - Select device with an off-state voltage rating ( $V_{DRM}$ ) above the maximum operating voltage at the minimum operating temperature.
- Select surge current ratings ( $I_{PPS}$  and  $I_{TSM}$ )  $\geq$  those which the application must withstand.
- Verify that the minimum holding current of the device at the maximum ambient temperature is above the maximum dc current of the system.
- Verify that the maximum breakover voltage of the device is below the system damage threshold.
- Verify that the circuit's ambient operating temperatures are within the device's operating temperature range.
- Verify that the device's dimensions fit the application's space considerations.
- Independently evaluate and test the suitability and performance of the device in the application

## MAXIMUM SURGE RATINGS ( $T_J = 25\text{ }^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Rating	Non-Repetitive Peak Pulse Current						Non-Repetitive Peak On-State Surge Current
Symbol	$I_{PPS}$						$I_{TSM}$
Short-Circuit Current Wave	2/10 $\mu\text{s}$	8/20 $\mu\text{s}$	10/160 $\mu\text{s}$	5/310 $\mu\text{s}$	10/560 $\mu\text{s}$	10/1000 $\mu\text{s}$	<b>30A</b>
Open-Circuit Voltage Wave	2/10 $\mu\text{s}$	1.2/50 $\mu\text{s}$	10/160 $\mu\text{s}$	10/700 $\mu\text{s}$	10/560 $\mu\text{s}$	10/1000 $\mu\text{s}$	
Value	<b>300 A</b>	<b>225 A</b>	<b>150 A</b>	<b>115 A</b>	<b>100 A</b>	<b>80 A</b>	
Notes	(1,2,4,5,6)						(1,2,3,4)

Notes:

- Thermal accumulation between successive surge tests is not allowed.
- The device under test initially must be in thermal equilibrium with  $T_J = 25\text{ }^\circ\text{C}$ .
- Test at 1 cycle, 60 Hz.
- Surge ratings are non-repetitive because instantaneous junction temperatures may exceed the maximum rated  $T_J$ . Nevertheless, devices will survive many surge applications without degradation. Surge capability will not degrade over a device's typical operating life.
- Adjust the surge generator for optimum current-wave accuracy when both voltage and current wave specifications cannot be exactly met. The current wave is more important than the voltage wave for accurate surge evaluation.
- The waveform is defined as A/B ms where:
  - A: (Virtual front time) =  $1.25 \times \text{Rise time} = 1.25 \times (T_b - T_a)$
  - B: (Duration time to 50% level of  $I_{pps}$ ) =  $T_1 - T_0$



**MAXIMUM THERMAL RATINGS**

Rating	Symbol	Value	Unit
Storage Junction Temperature Range	T <sub>STG</sub>	-50 to 150	°C
Operating Junction Temperature Range	T <sub>J</sub>	-40 to 150	°C
Operating Ambient Temperature Range	T <sub>a</sub>	-40 to 65	°C

Notes:

PCB board mounted on minimum foot print.

**THERMAL CHARACTERISTICS**

Characteristic	Symbol	Value	Unit
Thermal Resistance Junction to Leads T <sub>L</sub> on tab adjacent to plastic. Both leads soldered to identical pad sizes.	R <sub>θJL</sub>	Max. 20	°C / W

Notes:

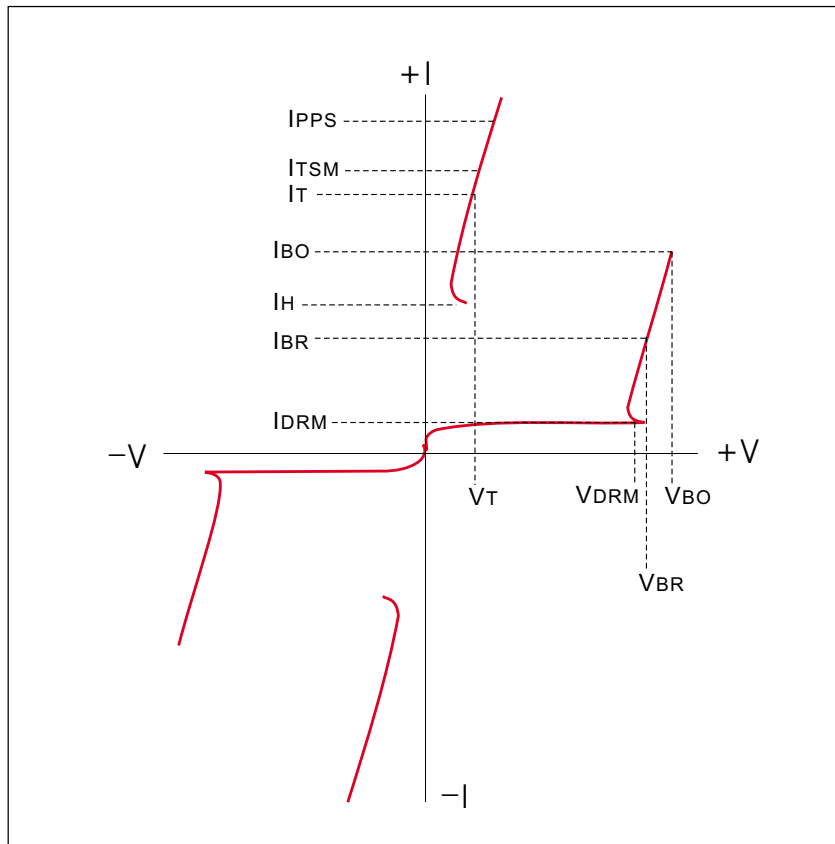
The junction to lead thermal resistance represents a minimum limiting value with both leads soldered to a large near-infinite heatsink. The junction to ambient thermal resistance depends strongly on board mounting conditions and typically is 3 to 6 times higher than the junction to lead resistance. The data shown is to be used as guideline values for preliminary engineering.

**ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = 25°C UNLESS OTHERWISE NOTED)**

Parameters	Test Conditions	Symbol	Min.	Max.	Unit
Repetitive Peak Off-State Current	V <sub>D</sub> = rated V <sub>DRM</sub>	I <sub>DRM</sub>		5	μA
Breakover Current	f = 60 Hz, I <sub>sc</sub> = 1 Arms, V <sub>ac</sub> = 1 KVrms, R <sub>L</sub> = 1 KΩ, 1/2 AC cycle	I <sub>BO</sub>		800	mA
Holding Current1	10/1000μs waveform, I <sub>sc</sub> = 10A, V <sub>oc</sub> = 62 V, R <sub>L</sub> = 400 Ω	I <sub>H</sub>	150		mA
On-State Voltage	I <sub>T</sub> = 1 A, T <sub>w</sub> = 300 μs, 1 pulse	V <sub>T</sub>		5	V

Notes:

Specific I<sub>H</sub> values are available by request.



Characteristic	Symbol	Value
$V_{BO}$	Breakover Voltage	Maximum voltage across the device in or at breakdown measured under a specified voltage and current rate of rise
$I_{BO}$	Breakover Current	Instantaneous current flowing at the breakover voltage ( $V_{BO}$ )
$I_H$	Holding Current	Minimum current required to maintain the device in the on-state
$I_T$	On-state current	Current through the device in the on-state condition
$V_T$	On-state voltage	Voltage across the device in the on-state condition at a specified current ( $I_T$ )
$V_{DRM}$	Rated Repetitive Peak Off-State Voltage	The highest instantaneous value of the off-state voltage, including all repetitive transient voltages but excluding all nonrepetitive transient voltages
$I_{DRM}$	Repetitive Peak Off-State Current	The maximum (peak) value of current that results from the application of $V_{DRM}$
$I_{PPS}$	Non-Repetitive Peak pulse current	Rated maximum value of peak impulse current of specified amplitude and waveshape that may be applied without damage to the device under test
$di/dt$	Critical rate of rise of on-state current	Rated value of the rate of rise of current that the device can withstand without damage.
$dv/dt$	Critical Rate of Rise of Off-State Voltage	The maximum rate of rise of voltage (below $V_{DRM}$ ) that will not cause switching from the off-state to the on-state.

## CAPACITANCE CHARACTERISTICS

F = 1 MHz, V<sub>ac</sub> = 15 mV<sub>rms</sub>

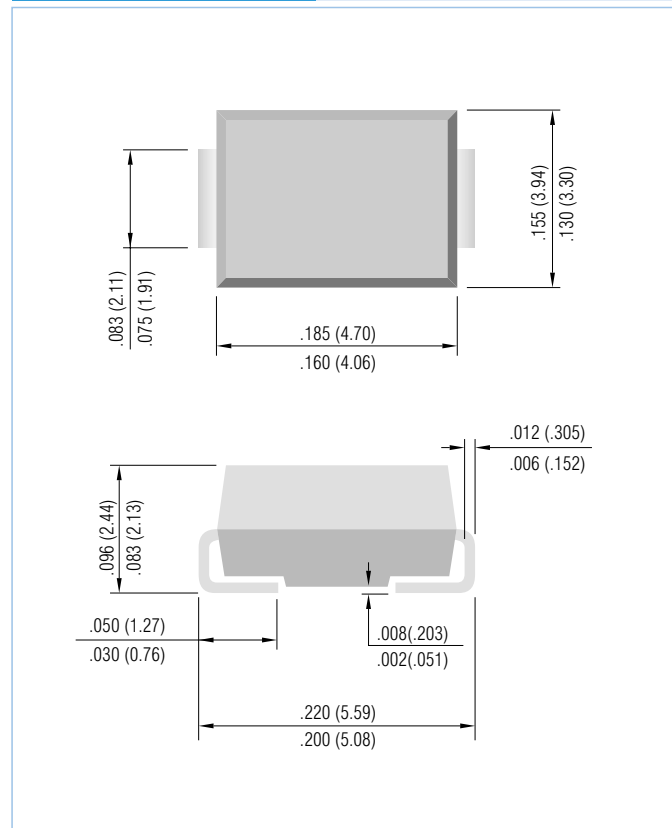
Part Number	Off-State Capacitance C <sub>o</sub>									
	pF									
	0 Vdc		1 Vdc		2 Vdc		5 Vdc		50 Vdc	
	Typ.	Max.	Typ.	Max.	Typ.	Max.	Typ.	Max.	Typ.	Max.
TSP058SB	70	100	59	74	53	68	45	59	24	29
TSP065SB	67	90	58	69	52	63	43	56	22	28
TSP075SB	67	78	56	64	49	58	42	49	23	27
TSP090SB	57	61	48	50	42	46	35	38	19	21
TSP120SB	50	58	42	45	38	50	31	33	17	20
TSP140SB	49	54	40	43	36	43	30	32	16	19
TSP160SB	46	53	38	40	34	36	28	30	15	18
TSP190SB	45	53	38	39	33	35	28	30	14	18
TSP220SB	44	52	37	39	32	35	27	30	13	18
TSP275SB	44	51	37	39	32	34	27	29	13	18
TSP320SB	43	50	37	38	32	34	27	29	13	17

## MECHANICAL DATA

- Case: JEDEC DO-214AA molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Bi-directional Standard packaging: 12mm tape (EIA-481)
- Weight: 0.003 ounce, 0.093 gram

### SMB / DO-214AA

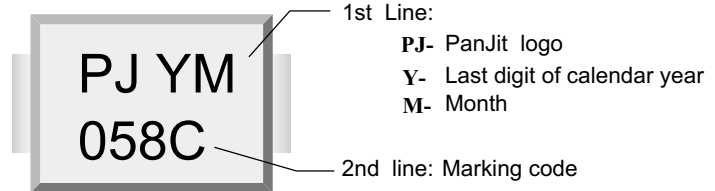
Unit: inch ( mm )



PRELIMINARY

**DEVICE MARKING CODE**

Part Number	Marking Code
TSP058SB	058B
TSP065SB	065B
TSP075SB	075B
TSP090SB	090B
TSP120SB	120B
TSP140SB	140B
TSP160SB	160B
TSP190SB	190B
TSP220SB	220B
TSP275SB	275B
TSP320SB	320B

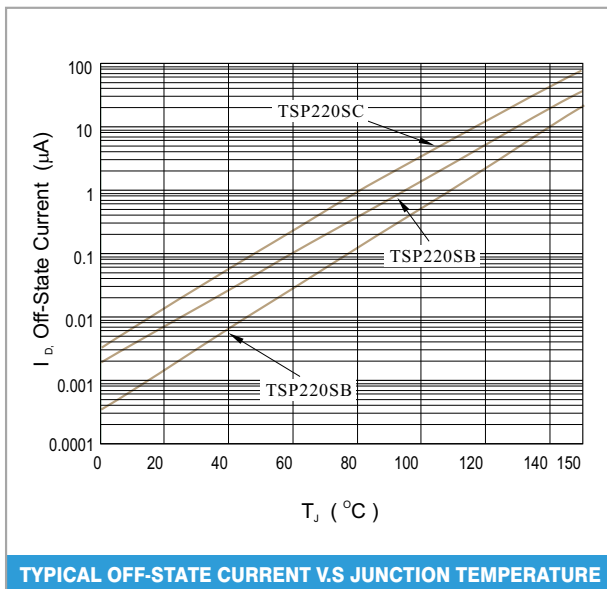
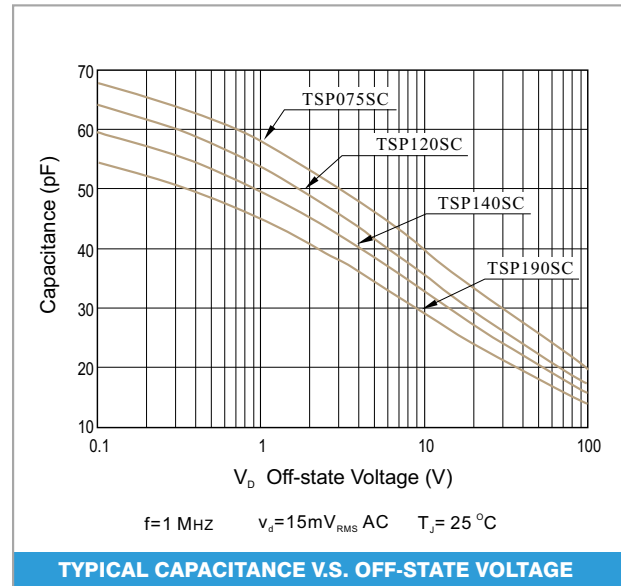
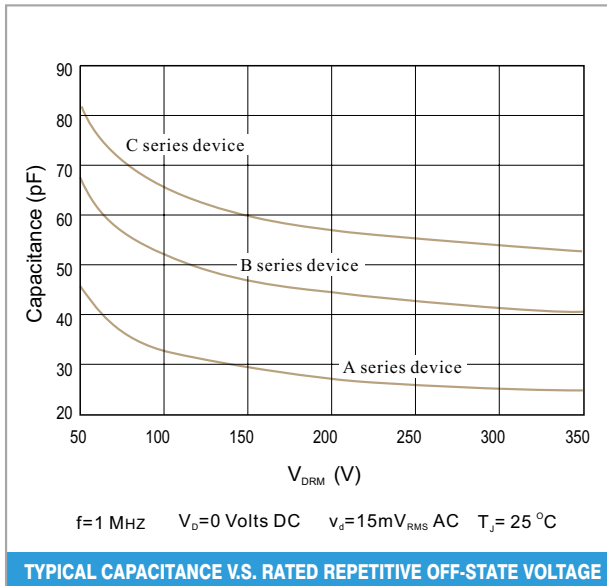


THYRISTOR  
| TSP058SB - TSP320SB |

**ORDER & PACKING INFORMATION**

Device	Packing	Min. Order Q'ty	Order As	Remark
TSPxxxSB	13" Tape & Reel	3,000 pcs	TSPxxxSB	Standard Packing
	7" Tape & Reel	500 pcs	TSPxxxSB-7	

## RATING AND CHARACTERISTIC CURVES



## IMPORTANT NOTICE

This information is intended to unambiguously characterize the product in order to facilitate the customer's evaluation of the device in the application. It will help the customer's technical experts determine that the device is compatible and interchangeable with similar devices made by other vendors. The information in this data sheet is believed to be reliable and accurate. The specifications and information herein are subject to change without notice. New products and improvements in products and their characterization are constantly in process. This provides a superior performing and the highest value product. The factory should be consulted for the most recent information and for any special characteristics not described or specified.

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